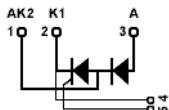


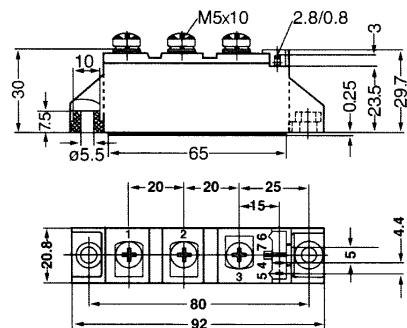
CTD27, CDT27

Thyristor-Diode Modules, Diode-Thyristor Modules



| Type | V_{RSM} V_{DSM} | V_{RRM} V_{DRM} |
|---------------|------------------------|------------------------|
| | V | V |
| CTD/CDT27GK08 | 900 | 800 |
| CTD/CDT27GK12 | 1300 | 1200 |
| CTD/CDT27GK14 | 1500 | 1400 |
| CTD/CDT27GK16 | 1700 | 1600 |
| CTD/CDT27GK18 | 1900 | 1800 |

Dimensions in mm (1mm=0.0394")



| Symbol | Test Conditions | Maximum Ratings | Unit |
|--|--|---------------------------------|------------------------|
| I_{TRMS} , I_{FRMS} I_{TAVM} , I_{FAVM} | $T_{VJ}=T_{VJM}$ $T_c=85^\circ\text{C}$; 180° sine | 50 27 | A |
| I_{TSM} , I_{FSM} | $T_{VJ}=45^\circ\text{C}$ $V_R=0$ | 520 560 | A |
| | $T_{VJ}=T_{VJM}$ $V_R=0$ | 460 500 | |
| $\int i^2 dt$ | $T_{VJ}=45^\circ\text{C}$ $V_R=0$ | 1350 1300 | A^2s |
| | $T_{VJ}=T_{VJM}$ $V_R=0$ | 1050 1030 | |
| $(di/dt)_{cr}$ | $T_{VJ}=T_{VJM}$ $f=50\text{Hz}$, $t_p=200\mu\text{s}$ $V_D=2/3V_{DRM}$ $I_G=0.45\text{A}$ | 150 | $\text{A}/\mu\text{s}$ |
| | repetitive, $I_T=45\text{A}$ non repetitive, $I_T=I_{TAVM}$ $dI/dt=0.45\text{A}/\mu\text{s}$ | 500 | |
| $(dv/dt)_{cr}$ | $T_{VJ}=T_{VJM}$; $V_{DR}=2/3V_{DRM}$ $R_{GK}=\infty$; method 1 (linear voltage rise) | 1000 | $\text{V}/\mu\text{s}$ |
| P_{GM} | $T_{VJ}=T_{VJM}$ $I_T=I_{TAVM}$ | 10 5 | W |
| P_{GAV} | | 0.5 | W |
| V_{RGM} | | 10 | V |
| T_{VJ} T_{VJM} T_{stg} | | -40...+125 125 -40...+125 | $^\circ\text{C}$ |
| V_{ISOL} | 50/60Hz, RMS $I_{ISOL}\leq 1\text{mA}$ | 3000 3600 | V_\sim |
| M_d | Mounting torque (M5) Terminal connection torque (M5) | 2.5-4.0/22-35 2.5-4.0/22-35 | Nm/lb.in. |
| Weight | Typical including screws | 90 | g |

D E E C o r p .

CTD27, CDT27

Thyristor-Diode Modules, Diode-Thyristor Modules

| Symbol | Test Conditions | Characteristic Values | Unit |
|--------------------|--|-----------------------|-----------|
| I_{RRM}, I_{DRM} | $T_{VJ}=T_{VJM}; V_R=V_{RRM}; V_D=V_{DRM}$ | 3 | mA |
| V_T, V_F | $I_T, I_F=80A; T_{VJ}=25^\circ C$ | 1.64 | V |
| V_{TO} | For power-loss calculations only ($T_{VJ}=125^\circ C$) | 0.85 | V |
| r_T | | 11 | $m\Omega$ |
| V_{GT} | $V_D=6V; T_{VJ}=25^\circ C$ $T_{VJ}=-40^\circ C$ | 1.5 1.6 | V |
| I_{GT} | $V_D=6V; T_{VJ}=25^\circ C$ $T_{VJ}=-40^\circ C$ | 100 200 | mA |
| V_{GD} | $T_{VJ}=T_{VJM}; V_D=2/3V_{DRM}$ | 0.2 | V |
| I_{GD} | | 10 | mA |
| I_L | $T_{VJ}=25^\circ C; t_p=10\mu s; V_D=6V$ $I_G=0.45A; dI/dt=0.45A/\mu s$ | 450 | mA |
| I_H | $T_{VJ}=25^\circ C; V_D=6V; R_{GK}=\infty$ | 200 | mA |
| t_{gd} | $T_{VJ}=25^\circ C; V_D=1/2V_{DRM}$ $I_G=0.45A; dI/dt=0.45A/\mu s$ | 2 | us |
| t_q | $T_{VJ}=T_{VJM}; I_T=20A; t_p=200\mu s; -dI/dt=10A/\mu s$ $V_R=100V; dv/dt=20V/\mu s; V_D=2/3V_{DRM}$ | typ. 150 | us |
| Q_s | $T_{VJ}=T_{VJM}; I_T, I_F=25A; -dI/dt=0.64A/\mu s$ | 50 | uC |
| I_{RM} | | 6 | A |
| R_{thJC} | per thyristor/diode; DC current per module | 0.88 0.44 | K/W |
| R_{thJK} | per thyristor/diode; DC current per module | 1.08 0.54 | K/W |
| ds | Creeping distance on surface | 12.7 | mm |
| da | Strike distance through air | 9.6 | mm |
| a | Maximum allowable acceleration | 50 | m/s^2 |

FEATURES

- * International standard package
- * Direct copper bonded Al₂O₃-ceramic base plate
- * Planar passivated chips
- * Isolation voltage 3600 V~
- * UL registered, E 72873
- * Gate-cathode twin pins for version 1

APPLICATIONS

- * DC motor control
- * Softstart AC motor controller
- * Light, heat and temperature control

ADVANTAGES

- * Space and weight savings
- * Simple mounting with two screws
- * Improved temperature and power cycling
- * Reduced protection circuits

D E E C o r p .

CTD27, CDT27

Thyristor-Diode Modules, Diode-Thyristor Modules

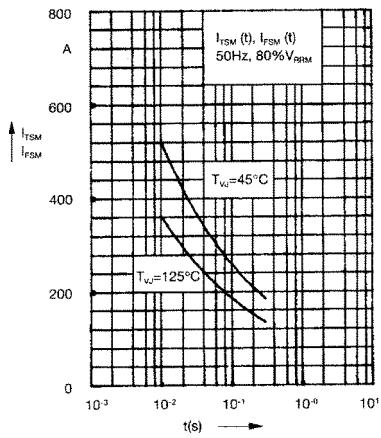


Fig. 1 Surge overload current
 I_{TSM}, I_{FSM} : Crest value, t: duration

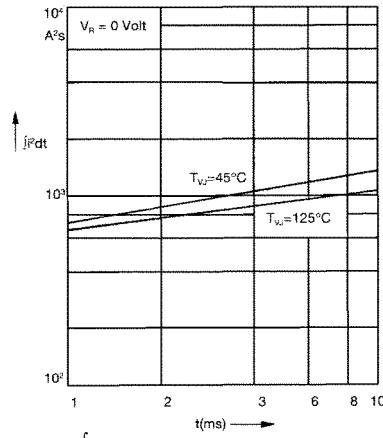


Fig. 2 $\int i^2 dt$ versus time (1-10 ms)

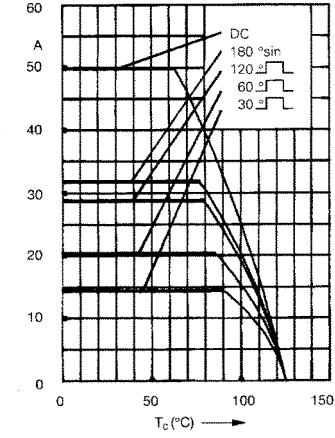


Fig. 2a Maximum forward current at case temperature

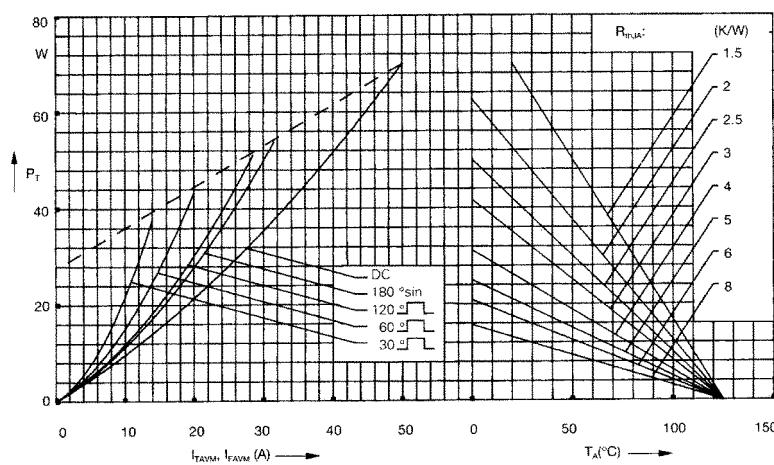


Fig. 3 Power dissipation versus on-state current and ambient temperature (per thyristor or diode)

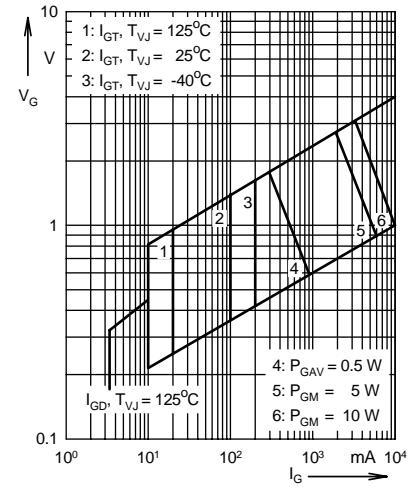


Fig. 4 Gate trigger characteristics

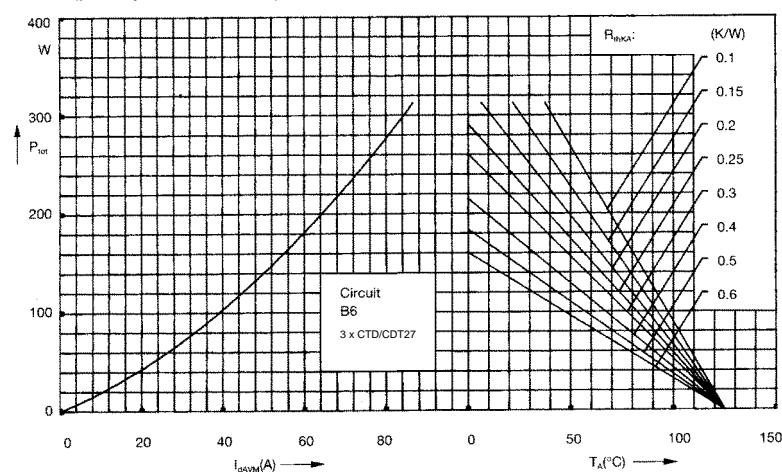


Fig. 5 Three phase rectifier bridge: Power dissipation versus direct output current and ambient temperature

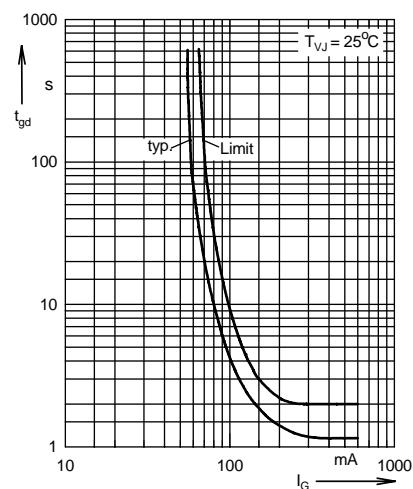


Fig. 6 Gate trigger delay time

D E E C o r p .

CTD27, CDT27

Thyristor-Diode Modules, Diode-Thyristor Modules

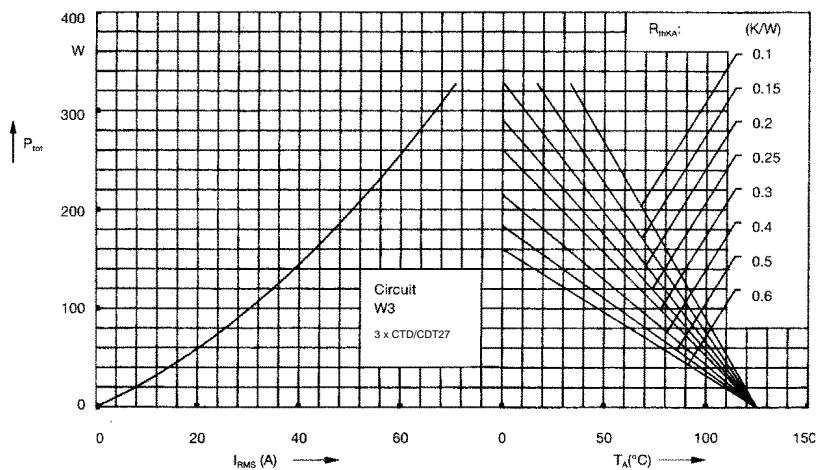


Fig. 7 Three phase AC-controller:
Power dissipation versus RMS
output current and ambient
temperature

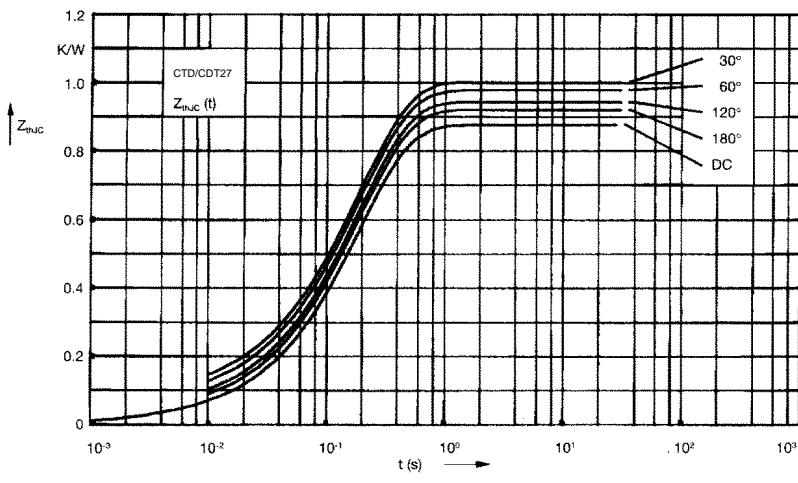


Fig. 8 Transient thermal impedance
junction to case (per thyristor or
diode)

R_{thJC} for various conduction angles d :

| d | R_{thJC} (K/W) |
|------|------------------|
| DC | 0.88 |
| 180° | 0.92 |
| 120° | 0.95 |
| 60° | 0.98 |
| 30° | 1.01 |

Constants for Z_{thJC} calculation:

| i | R_{thi} (K/W) | t_i (s) |
|-----|-----------------|-----------|
| 1 | 0.019 | 0.0031 |
| 2 | 0.029 | 0.0216 |
| 3 | 0.832 | 0.191 |

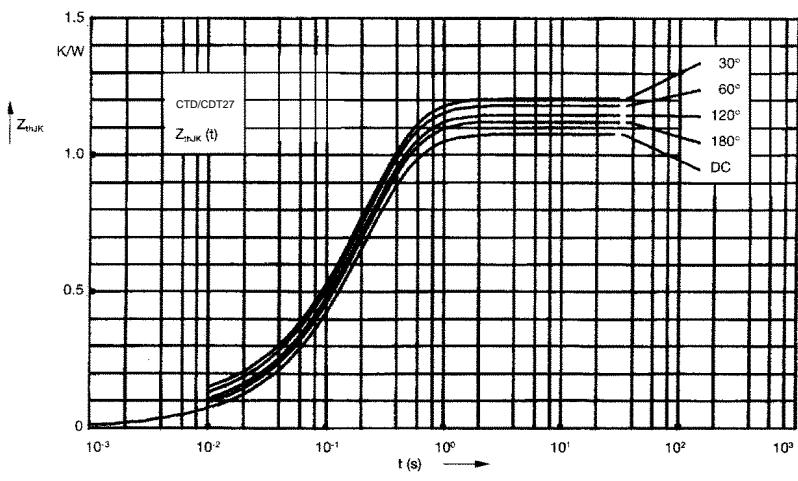


Fig. 9 Transient thermal impedance
junction to heatsink (per thyristor or
diode)

R_{thJK} for various conduction angles d :

| d | R_{thJK} (K/W) |
|------|------------------|
| DC | 1.08 |
| 180° | 1.12 |
| 120° | 1.15 |
| 60° | 1.18 |
| 30° | 1.21 |

Constants for Z_{thJK} calculation:

| i | R_{thi} (K/W) | t_i (s) |
|-----|-----------------|-----------|
| 1 | 0.019 | 0.0031 |
| 2 | 0.029 | 0.0216 |
| 3 | 0.832 | 0.191 |
| 4 | 0.2 | 0.45 |

D E E C o r p .